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### PNP PRE-BIASED 500mA TRANSISTOR

## Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDTD)
- Built-In Biasing Resistors
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative.
  - https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
  Lead Free Plating (Matte Tin Finish Annealed over Alloy 42 Leadframe).
- Marking Information: See Table Below & Page 3
- Ordering Information: See Page 3
- Weight: 0.008 grams (Approximate)

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	SOT-23	
Dim	Min	Мах
Α	0.37	0.51
В	1.20	1.40
С	2.30	2.50
D	0.89	1.03
E.	0.45	0.60
G	1.78	2.05
Н	2.80	3.00
J	0.013	0.10
К	0.903	1.10
L.	0.45	0.61
М	0.085	0.180
α	0°	8°
All Dim	ensions	in mm

Schematic and Pin Diagram

GND(+)

IN

P/N	R1 (NOM)	R2 (NOM)	Type Code
DDTB122LC	0.22kΩ	10kΩ	P75
DDTB142JC	0.47kΩ	10kΩ	P76
DDTB122TC	0.22kΩ	OPEN	P77
DDTB142TC	0.47kΩ	OPEN	P78

## Maximum Ratings @T<sub>A</sub> = +25°C, unless otherwise specified.

Characteristic		Symbol	Value	Unit
Supply Voltage, (3) to (2)		Vcc	-50	V
Input Voltage, (1) to (2)	DDTB122LC DDTB142JC	V <sub>IN</sub>	+5 to -6 +5 to -6	V
Input Voltage, (2) to (1)	DDTB122TC DDTB142TC	V <sub>EBO (MAX)</sub>	-5	V
Output Current	All	Ic	-500	mA
Power Dissipation	(Note 4)	P <sub>D</sub>	200	mW
Thermal Resistance, Junction to Ambient Air	(Note 4)	$R_{ ext{ heta}JA}$	625	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/package-outlines.html.



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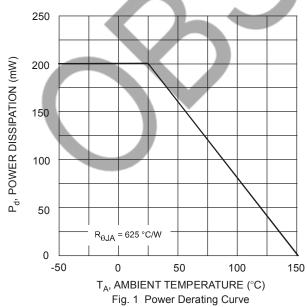
**R1- Only Types** 

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	DDTB122LC DDTB142JC	V <sub>l(off)</sub>	-0.3 -0.3				V <sub>CC</sub> = -5V, I <sub>O</sub> = -100μA
	DDTB122LC DDTB142JC	VI(on)			-2.0 -2.0	V	V <sub>O</sub> = -0.3V, I <sub>O</sub> = -20mA V <sub>O</sub> = -0.3V, I <sub>O</sub> = -20mA
Output Voltage		V <sub>O(on)</sub>	—	_	-0.3V	V	I <sub>O</sub> /I <sub>I</sub> = -50mA/-2.5mA
Input Current	DDTB122LC DDTB142JC	lı	_	_	-28 -13	mA	V <sub>1</sub> = -5V
Output Current		I <sub>O(off)</sub>	_	_	-0.5	μA	V <sub>CC</sub> = -50V, V <sub>I</sub> = 0V
DC Current Gain	DDTB122LC DDTB142JC	GI	56 56	_	_	_	V <sub>O</sub> = -5V, I <sub>O</sub> = -50mA
Gain-Bandwidth Product*		f⊤	_	200	_	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = -5mA, f = 100MHz

# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

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Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV <sub>CBO</sub>	-50		-	V	I <sub>C</sub> = -50μA
Collector-Emitter Breakdown Voltage	9	BV <sub>CEO</sub>	-40		—	V	I <sub>C</sub> = -1mA
Emitter-Base Breakdown Voltage	DDTB122TC DDTB142TC	BV <sub>EBO</sub>	-5	_		v	I <sub>E</sub> = -50μA I <sub>E</sub> = -50μA
Collector Cutoff Current		Ісво		_	-0.5	μA	V <sub>CB</sub> = -50V
Emitter Cutoff Current	DDTB122TC DDTB142TC	I <sub>EBO</sub>	Ξ.		-0.5 -0.5	μA	V <sub>EB</sub> = -4V
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>		_	-0.3	V	I <sub>C</sub> = -50mA, I <sub>B</sub> = -2.5mA
DC Current Transfer Ratio	DDTB122TC DDTB142TC	h <sub>FE</sub>	100 100	250 250	600 600		I <sub>C</sub> = -5mA, V <sub>CE</sub> = -5V
Gain-Bandwidth Product*		fτ	_	200	_	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = 5mA, f = 100MHz

\* Transistor - For Reference Only



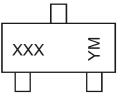


## Ordering Information (Note 5)

Part Number	Packaging	Shipping
DDTB122LC-7-F	SOT-23	3000/Tape & Reel
DDTB142JC-7-F	SOT-23	3000/Tape & Reel
DDTB122TC-7-F	SOT-23	3000/Tape & Reel
DDTB142TC-7-F	SOT-23	3000/Tape & Reel

Note: 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# Marking Information



XXX = Product Type Marking Code, See Table on Page 1 YM = Date Code Marking Y = Year ex: I = 2021 M = Month ex: 9 = September

### Date Code Key

Year	2006		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	Т			J	K	Γ	M	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec





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